Short range order in Ge-As-Se glasses

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Abstract
The structure of GeₓAs₁₀Se₉₀₋ₓ (x=10, 17.5, 22.5, 27.5, 30, 35) glasses as well as some other compositions extensively used in infrared optics, e.g. GASIR® (Ge₂₂As₂₀Se₅₈) and AMTIR-1 (Ge₃₃As₁₂Se₅₅) has been investigated by X-ray diffraction (XRD) and extended X-ray absorption fine structure (EXAFS) measurements at the Ge, As and Se K-edges. Structural models have been obtained by fitting simultaneously XRD and EXAFS data by the reverse Monte Carlo simulation technique. Unlike other IV-VI glasses (e.g. Ge-As-S, Ge-Sb-Te, Ge-Sb-Se, Ge-As-Te) Ge-As-Se glasses are characterized by the lack of preferential bonding and behave as random covalent networks: Ge-Ge, Ge-As or As-As bonds can be found in Se-rich compositions while Se-Se bonding remains in strongly Se-deficient glasses as well.

PACS numbers: 61.43.Dq, 61.05.cj, 61.05.cp, 61.05.fm

Keywords: chalcogenide glasses; Ge-As-Se; structure; bonds; XRD; EXAFS; RMC

1. Introduction
In the last few years chalcogenide glasses have received renewed attention because of their prominent optical properties: low optical absorption in the mid infrared region and high linear and nonlinear refractive indices [1, 2]. Chalcogenide glasses have nonlinearity several orders of magnitude greater than silica glass, which makes them useful for all-optical processing of telecommunication signals at extreme speeds [3, 4]. Chalcogenide glass optical fibers are employed in numerous devices, for example in IR optical fiber lasers and amplifiers [5, 6],
Raman lasers [7, 8] or fiber-based chemical and biomedical sensor devices [9-12]. Several other applications were considered, such as medical endoscopy [13], environmental metrology [14] or spatial interferometry. Single mode fibers, operating in the 4-20 μm range were proposed for space research in the frame of the Darwin mission [15].

Among the different families of chalcogenide glasses, the Ge-As-Se system is particularly interesting due to its very broad glass formation region, which also means the tunability of their physical and optical properties by the chemical composition. The most important parameter characterizing a chalcogenide glassy network is the mean coordination number MCN, defined as the sum of the respective elemental concentrations times their coordination number. Many physical properties of chalcogenide glasses have been found to correlate with the MCN. A transition at MCN around 2.4 from an underconstrained ‘floppy’ to an overconstrained ‘rigid’ network has been found by mean field theory using constraint counting [16,17]. Tanaka suggested that a second transition from a topologically two-dimensional structure to a three-dimensional network may occur at the average coordination number of 2.67 [18]. A large number of experiments demonstrated that many chemical and physical properties change abruptly at these MCN values [19, 20]. Random networks, in which stressed configurations are avoided if possible, show two transitions and an intermediate state that is rigid but stress-free [21]. By temperature-modulated differential scanning calorimetry and Raman scattering measurements a thermally reversing compositional window was reported, where the glasses are generally non-aging [22, 23].

To assess the validity of mean field approximations and to learn more about the structure of Ge-As-Se glasses in general, it is essential to know their chemical short range order. Compositions with 5 and 15 at.% Ge have been studied recently [24] by fitting X-ray diffraction measurements simultaneously with Ge, As and Se K-edge extended X-ray absorption fine structure (EXAFS) datasets in the framework of the reverse Monte Carlo simulation technique (RMC) [25-27]. It has been found that the glasses investigated (with values of MCN up to 2.64) can be characterized as random covalent networks: bonds between Ge and As (Ge-Ge, As-As, As-Ge) can be found in compositions with excess Se while Se-Se bonds persist in the strongly Se-deficient region.

It is important to know whether the lack of chemical short range order is characteristic of low (5-15%) Ge content glasses only or persists over a wider composition range. For this reason we investigate the structure of Ge-As-Se glasses up to 35% Ge content. Similarly to our previous study, large scale structural models are obtained by fitting simultaneously X-ray diffraction and EXAFS measurements (4 datasets for each composition) with the reverse
Monte Carlo technique. Short range order parameters (bond lengths, coordination numbers) are discussed in detail and compared with those of other IV-VI glasses.

2. Experimental details
The X-ray diffraction measurements of Ge$_{22}$As$_{20}$Se$_{58}$, Ge$_{33}$As$_{12}$Se$_{35}$ and Ge$_{33}$As$_{20}$Se$_{47}$ were carried out at the BW5 experimental station at HASYLAB (DESY, Hamburg, Germany). The Ge, As and Se K-edge EXAFS spectra of the above compositions and those of the Ge$_{x}$As$_{10}$Se$_{90-x}$ series were measured at beamline X1 of HASYLAB. For the details of the above experiments and that of the sample preparation we refer to some recent publications [24, 28]. Glass compositions were determined using energy dispersive spectroscopy. Polished samples were measured at three different positions and the results were averaged. The difference between the nominal and the experimental compositions is less than 0.5%.

X-ray diffraction structure factors of the Ge$_{x}$As$_{10}$Se$_{90-x}$ glasses were measured at the P07 high energy materials science beamline [29] at PETRA III synchrotron storage ring (DESY, Hamburg, Germany). The radiation of the undulator source was monochromatized by a double crystal monochromator consisting of two bent Si(111) Laue crystals. The energy of the monochromatic radiation was 100.0 keV. Bulk pieces of Ge-As-Se glasses (1-1.5 mm thickness) were measured in transmission mode. Each sample was illuminated for 10x5 seconds. The size of the incident beam was 0.25x0.25 mm$^2$.

Scattered intensities were measured by a 2D detector (Perkin-Elmer XRD 1622). The sample-detector distance was 289.4 mm. Raw intensities were corrected for background and polarization and integrated to $Q$-space by the program Fit2D [30]. The integrated data were corrected for Compton-scattering [31]. Some selected structure factors $S(Q)$ and the corresponding $k^4$-weighted $\chi(k)$ curves are shown in Figures 1 and 2.

3. Reverse Monte Carlo simulation
Model configurations were obtained by fitting simultaneously the Ge, As, Se K-edge EXAFS data and the XRD structure factor for each composition. Though RMC was used first with diffraction data [25] it was practically immediately implemented for EXAFS [32]. Technical details of using EXAFS data in RMC modeling are discussed in refs. 27 and 32.

Simulation boxes contained 20000 atoms. Densities were taken from refs. [19, 28]. Initial configurations were obtained in two steps: 1) atoms were placed at random in the simulation box; 2) atoms were moved around until their separations were higher than the
minimum interatomic distances. The minimum interatomic distances were usually equal to 2.2 Å if bonding was allowed and 2.9 Å in case of forbidden bonds (see e.g. 4.2.). The maximum random displacement was 0.1 Å along each coordinate. In accordance with the ‘8-N’ rule [34], the total coordination numbers of Ge, As and Se were forced to be 4, 3 and 2, respectively. \( N_i \), the total coordination number of the \( i \)th component is defined as the sum of \( N_{ij} \), the average number of \( j \) type neighbors around \( i \) type atoms. We note here that the validity of the ‘8-N’ rule in IV-V-VI glasses have been confirmed by several studies [35-38]. The above coordination constraints were fulfilled generally by ~95% of the atoms.

As only the 3 total coordination numbers (\( N_i \)) were fixed, the type of neighbors (\( N_{ij} \)) could vary within the limits allowed by the constraints. In a three-component system there are 6 independent \( N_{ij} \) values. Therefore the system has considerable freedom and \( N_{ij} \) values are fixed by the information content of the experimental data. Configurations obtained by using the 3 total coordination number constraints were used as references for assessing the validity of models applying various additional constraints.

The uncertainty of \( N_{ij} \) coordination numbers is around 0.3-0.4. This value was obtained by dedicated simulation runs, in which test coordination constraints were used to change systematically the given \( N_{ij} \), starting from the values of the reference configurations. The cumulative relative \( R \)-factors (\( R_c \)) were used to quantify the overall quality of the fits. The \( R \)-factor of a given dataset (either EXAFS or X-ray diffraction) is defined by the following equation:

\[
R = \sqrt{\frac{\sum_i (S_{mod}(k_i) - S_{exp}(k_i))^2}{\sum_i S_{exp}^2(k_i)}}
\]

(1),

where \( S_{mod} \) and \( S_{exp} \) are the model and experimental structure factors (or EXAFS curves), \( k_i \) denotes the experimental points. Relative \( R \)-factors are obtained by dividing the given \( R \)-factor with that of the \( R \)-factor of the same dataset in the reference model. We have selected the ‘all bonds allowed’ model as a reference for all compositions. Finally, \( R_c \) is given as the sum of the relative \( R \)-factors of the X-ray diffraction and EXAFS experiments divided by 4, the number of datasets fitted. Thus, \( R_c \) of the reference models is 1 by definition.

The uncertainty of bond lengths is about ±0.02 Å in case of mixed indices (Ge-As, Ge-Se, As-Se). These pairs directly contribute to two EXAFS spectra that keep their error at a relatively low level. The uncertainty of the distances of like atoms (Ge-Ge, As-As, Se-Se) is usually somewhat higher and depends strongly on the concentration of the given atom.
The quality of the fits is exemplified by Figures 3 and 4 where the experimental and model XRD and EXAFS curves of Ge$_{27.5}$As$_{10}$Se$_{62.5}$ are compared. Partial pair correlation functions of the same composition are shown in Figure 5. First peaks are well defined and very close to each other. (Nearest neighbor distances are within 0.10-0.13 Å for all compositions (Table 1).) The separation of so strongly overlapping peaks is possible only by combining the information provided by multiple experimental datasets.

4. Discussion
Nearest neighbor distances and coordination numbers of the Ge-As-Se glasses investigated are given in Tables 1 and 2, respectively. It can be observed that Ge-Ge, Ge-As or As-As bonds can be found even in strongly Se-rich alloys while Se-Se bonds persist in Se-poor compositions. (A glass with composition Ge$_x$As$_y$Se$_{1-x-y}$ is Se-rich if $2(1-x-y) > 4x+3y$. In case of equality the composition is stoichiometric, while it is Se-poor if $2(1-x-y) < 4x+3y$.) We carried out dedicated simulation runs to check whether the existence of the homonuclear Ge-Ge and As-As and heteronuclear Ge-As bonds is a simulation artefact or necessary to fit the experimental datasets. To achieve this goal we have created models in which these bonds were forbidden in various combinations.

4.1. Bonds between Ge and As in Se-rich glasses
The existence of Ge-Ge, Ge-As and As-As bonds was investigated in Ge$_{10}$As$_{10}$Se$_{80}$, the highest Se-content glass. $R_c$ values of various models are given in Table 3. It was found that As-As bonding has a negligible effect on the quality of fits. The simultaneous elimination of As-As and Ge-Ge bonds results in a 5.7% increase of $R_c$. If all of Ge-Ge, Ge-As and As-As bonds were eliminated, $R_c$ became as high as 1.29.

It can thus be concluded that in case of Ge$_{10}$As$_{10}$Se$_{80}$ As-As bonds are not needed to reproduce experimental data but fit quality drastically deteriorates if Ge-As bonds are eliminated. The reliability of this finding is also supported by the stability of Ge-As distance, which is 2.45-2.46 Å over the whole – very broad – composition range investigated (Table 1). This is the longest bond length, therefore the lack of Ge-As bonds cannot be compensated (without worsening fit quality) by an increase of other coordination numbers. On the other hand, As-As and Ge-Ge distances are somewhat more scattered suggesting that their fluctuations may be set off by changes in other distances.

We also note that Ge$_{10}$As$_{10}$Se$_{80}$ is strongly Se-rich, therefore elimination of bonds between minor components alone should not bring about drastic changes fit quality.
increase of $R_e$ in the corresponding model clearly shows that Ge-As pairs are present in the glass.

4.2. Se-Se bonds in the strongly Se-deficient region
Models with and without Se-Se bonds were investigated to test whether Se-Se bonding is necessary to get a reasonable fit of experimental data of Ge$_{33}$As$_{20}$Se$_{47}$, the most Se-deficient glass. Se-Se bonding was eliminated by setting the corresponding minimum interatomic distance to 2.9 Å. It has been found that Se-Se bonds do improve the quality of the fit of Se K-edge EXAFS data even in this composition. The cumulative relative $R$-factor of the Se-Se bonding-free model was as high as 1.299. Fits of Se K-edge EXAFS data with and without Se-Se bonds are compared in Figure 6.

4.3. Comparison with other IV-VI glasses
Detailed structural investigations of Ge-Sb-Te [35, 36] and Ge-Sb-Se glasses [39] have shown that chalcogen-metal bonds have the highest priority and Ge/Sb-Ge/Sb bonds are formed only if there are no more available chalcogen atoms. The coordination numbers of Ge$_{22}$As$_{20}$Se$_{58}$ (also known as GASIR®) and Ge$_2$Sb$_2$Te$_5$ are compared in Table 4, where the coordination numbers of the respective IV-VI random covalent networks are also given. In such a network $N_{ij}$ coordination numbers are determined solely by the $N_i$ total coordination numbers and the $c_j$ atomic fractions of the constituents:

$$N_{ij} = \frac{c_j N_i N_j}{\sum c_k N_k}$$

It can be observed that Ge$_2$Sb$_2$Te$_5$ is characterized by pronounced chemical short range order: Te-Te bonds are absent and Ge/Sb-Ge/Sb bonds are formed only in the absence of free Te atoms. On the other hand, coordination numbers of Ge$_{22}$As$_{20}$Se$_{58}$ do not deviate significantly from the corresponding values of the random covalent network. In Table 2 the random values are given for all compositions (values in parentheses). In most cases they agree with the experiment-based values within their uncertainty, showing the lack of strong chemical ordering in Ge-As-Se glasses.

This observation is in contrast with the behavior of other IV-VI glasses. Various experimental studies revealed that chemical ordering is very pronounced in the Ge-As-S system as well. Sen et al investigated the structure of Ge$_x$As$_y$S$_{1-x-y}$ glasses with $x:y = 1:2$, 1:1,
and 2.5:1 over a wide-ranging S content [40]. It was found that upon decreasing the S content first As-As bonds appear, while Ge takes part in metal-metal bonds only in strongly S-poor compositions. A combined neutron and X-ray diffraction study of Ge$_x$As$_x$S$_{100-2x}$ glasses [41] gave similar conclusions.

The structure of Ge-As-Te glasses has also been investigated by the combination of diffraction techniques, EXAFS and reverse Monte Carlo simulation [42]. It has been reported that Te-Te bonds can be found in strongly Te-deficient compositions while As-As bonds exist in Te-rich glasses. On the other hand, Ge-Ge bonding seems to be avoided even in Te-poor compositions which is a clear sign of chemical ordering around Ge. In view of these findings the complete lack of chemical short range order in Ge-As-Se glasses should be regarded as an anomaly.

4.4. Chemical short-range order and optical nonlinearity

The physical properties of Ge-As-Se glasses have been shown to vary remarkably with either the Ge-concentration or the theoretical mean coordination number [43, 44]. For example, the nonlinear refractive index $n_2$ of the Ge–As–Se glasses plotted as a function of the mean coordination number exhibits a minimum at the MCN values of about 2.7-2.8 [44] (Fig. 7a). It has been shown in [24] that there is a correlation between the behavior of the nonlinear refractive index and the total number of Ge-Ge, As-As, Se-Se and Ge-As bonds in Ge$_5$As$_x$Se$_{95-x}$ and Ge$_{15}$As$_x$Se$_{85-x}$ glasses. In the present study we have calculated the fractions of the above bonds (denoted with $\phi_{ij}$) in the Ge$_x$As$_{10}$Se$_{90-x}$ series and plotted $\phi_{GeGe} + \phi_{GeAs}$ and $\phi_{SeSe}$ as a function of the mean coordination number in Fig. 7b. For each constituent, $\phi_{ij}$ has been determined as a ratio of the respective bonds $(c_i N_{ij})$ to the total number of bonds in the simulation box:

$$\phi_{ij} = \frac{c_i N_{ij}}{N_i}.$$  \hspace{1cm} (3)

There is a good agreement in the dependences of the nonlinear refractive index $n_2$ and the total fraction of Ge-Ge, As-As, Se-Se and Ge-As bonds $\phi_{tot}$ (compare Fig. 7a and 7b). This supports the suggestion of Harbold et al [45] that the nonlinearity is influenced by both the presence of unpaired electrons and defect states in glasses. Indeed, the lone electron pairs may play a dominant role for achieving large nonlinearities in the Se-rich glasses where the
fraction of Se-Se bonds is large (triangles in Fig. 7b), whereas Ge-Ge and Ge-As bonds (squares in Fig. 7b) may contribute to the increasing nonlinearity in Se-poor glasses.

5. Summary
The structure of several Ge-As-Se glasses with mean coordination numbers between 2.20 and 2.86 has been investigated by X-ray diffraction and EXAFS at the Ge, As and Se K-edges. Structural models have been obtained by fitting the experimental datasets by the reverse Monte Carlo simulation technique. It has been found that various bonds between Ge and As (Ge-Ge, As-As, As-Ge) exist in Se-rich compositions while Se-Se bonds persist in strongly Se-deficient alloys. Unlike other IV-V-VI glass systems (e.g. Ge-As-S, Ge-As-Te, Ge-Sb-Te, Ge-Sb-Se) there is no significant chemical short range order in Ge-As-Se glasses.

Acknowledgments
This research was partly supported by the Australian Research Council through its Centres of Excellence and Discovery (DP110102753) programs. P. Jóvári is indebted to the Hungarian Basic Research Fund (OTKA) for financial support (Grant No. 083529).
References


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Table 1. Nearest neighbor distances in the Ge-As-Se glasses investigated

<table>
<thead>
<tr>
<th>Pair i-j</th>
<th>10-10-80</th>
<th>17.5-10-72.5</th>
<th>22.5-10-67.5</th>
<th>22-20-58</th>
<th>27.5-10-62.5</th>
<th>30-10-60</th>
<th>33-12-55</th>
<th>35-10-55</th>
<th>33-20-47</th>
</tr>
</thead>
<tbody>
<tr>
<td>Ge-Ge</td>
<td>2.39</td>
<td>2.42</td>
<td>2.36</td>
<td>2.38</td>
<td>2.40</td>
<td>2.37</td>
<td>2.39</td>
<td>2.42</td>
<td>2.41</td>
</tr>
<tr>
<td>Ge-As</td>
<td>2.45</td>
<td>2.46</td>
<td>2.45</td>
<td>2.45</td>
<td>2.45</td>
<td>2.46</td>
<td>2.46</td>
<td>2.46</td>
<td>2.46</td>
</tr>
<tr>
<td>Ge-Se</td>
<td>2.35</td>
<td>2.34</td>
<td>2.37</td>
<td>2.36</td>
<td>2.35</td>
<td>2.36</td>
<td>2.36</td>
<td>2.35</td>
<td>2.35</td>
</tr>
<tr>
<td>As-As</td>
<td>2.39</td>
<td>2.42</td>
<td>2.35</td>
<td>2.40</td>
<td>2.41</td>
<td>2.37</td>
<td>2.44</td>
<td>2.43</td>
<td>2.42</td>
</tr>
<tr>
<td>As-Se</td>
<td>2.39</td>
<td>2.36</td>
<td>2.39</td>
<td>2.39</td>
<td>2.37</td>
<td>2.37</td>
<td>2.38</td>
<td>2.38</td>
<td>2.37</td>
</tr>
<tr>
<td>Se-Se</td>
<td>2.35</td>
<td>2.37</td>
<td>2.33</td>
<td>2.35</td>
<td>2.33</td>
<td>2.33</td>
<td>2.33</td>
<td>2.33</td>
<td>2.33</td>
</tr>
</tbody>
</table>

Table 2. Coordination numbers of the Ge-As-Se glasses investigated. The values of the corresponding random covalent networks are given in parentheses (see section 4.3.)

<table>
<thead>
<tr>
<th>Pair i-j</th>
<th>10-10-80</th>
<th>17.5-10-72.5</th>
<th>22.5-10-67.5</th>
<th>22-20-58</th>
<th>27.5-10-62.5</th>
<th>30-10-60</th>
<th>33-12-55</th>
<th>35-10-55</th>
<th>33-20-47</th>
</tr>
</thead>
<tbody>
<tr>
<td>Ge-Ge</td>
<td>1.07(0.70)</td>
<td>1.34(1.14)</td>
<td>1.68(1.41)</td>
<td>1.46(1.33)</td>
<td>1.84(1.66)</td>
<td>2.04(1.78)</td>
<td>1.96(1.90)</td>
<td>2.18(2.00)</td>
<td>1.93(1.85)</td>
</tr>
<tr>
<td>Ge-As</td>
<td>0.62(0.52)</td>
<td>0.59(0.49)</td>
<td>0.52(0.47)</td>
<td>0.88(0.91)</td>
<td>0.47(0.45)</td>
<td>0.45(0.44)</td>
<td>0.52(0.52)</td>
<td>0.43(0.43)</td>
<td>0.86(0.84)</td>
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<tr>
<td>Ge-Se</td>
<td>2.35(2.78)</td>
<td>2.11(2.37)</td>
<td>1.82(2.12)</td>
<td>1.69(1.76)</td>
<td>1.72(1.89)</td>
<td>1.53(1.78)</td>
<td>1.55(1.58)</td>
<td>1.41(1.57)</td>
<td>1.24(1.31)</td>
</tr>
<tr>
<td>As-Ge</td>
<td>0.62(0.52)</td>
<td>1.03(0.86)</td>
<td>1.18(1.06)</td>
<td>0.96(1.00)</td>
<td>1.30(1.25)</td>
<td>1.35(1.33)</td>
<td>1.43(1.42)</td>
<td>1.51(1.50)</td>
<td>1.42(1.38)</td>
</tr>
<tr>
<td>As-As</td>
<td>0.32(0.39)</td>
<td>0.41(0.37)</td>
<td>0.36(0.35)</td>
<td>0.66(0.68)</td>
<td>0.30(0.34)</td>
<td>0.39(0.33)</td>
<td>0.36(0.39)</td>
<td>0.28(0.32)</td>
<td>0.57(0.63)</td>
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<tr>
<td>As-Se</td>
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<td>1.65(1.78)</td>
<td>1.49(1.59)</td>
<td>1.41(1.32)</td>
<td>1.42(1.42)</td>
<td>1.25(1.33)</td>
<td>1.23(1.19)</td>
<td>1.23(1.18)</td>
<td>0.99(0.99)</td>
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<tr>
<td>Se-Ge</td>
<td>0.29(0.35)</td>
<td>0.51(0.57)</td>
<td>0.61(0.71)</td>
<td>0.64(0.67)</td>
<td>0.76(0.83)</td>
<td>0.77(0.89)</td>
<td>0.93(0.95)</td>
<td>0.90(1.00)</td>
<td>0.87(0.92)</td>
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<tr>
<td>Se-As</td>
<td>0.27(0.26)</td>
<td>0.23(0.24)</td>
<td>0.22(0.24)</td>
<td>0.48(0.45)</td>
<td>0.23(0.23)</td>
<td>0.21(0.22)</td>
<td>0.27(0.26)</td>
<td>0.22(0.21)</td>
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<tr>
<td>Se-Se</td>
<td>1.49(1.39)</td>
<td>1.34(1.18)</td>
<td>1.16(1.06)</td>
<td>0.93(0.88)</td>
<td>1.02(0.94)</td>
<td>1.00(0.89)</td>
<td>0.83(0.79)</td>
<td>0.86(0.79)</td>
<td>0.66(0.66)</td>
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<td>MCN</td>
<td>2.30</td>
<td>2.45</td>
<td>2.55</td>
<td>2.64</td>
<td>2.65</td>
<td>2.70</td>
<td>2.78</td>
<td>2.80</td>
<td>2.86</td>
</tr>
<tr>
<td>Se-rich/poor</td>
<td>+0.45</td>
<td>+0.225</td>
<td>+0.075</td>
<td>-0.16</td>
<td>-0.075</td>
<td>-0.15</td>
<td>-0.29</td>
<td>-0.3</td>
<td>-0.49</td>
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</table>

Table 3. Cumulative relative R-factors (see the text for definition) of various models of Ge\textsubscript{10}As\textsubscript{10}Se\textsubscript{80}

<table>
<thead>
<tr>
<th>Model</th>
<th>reference</th>
<th>As-As forbidden</th>
<th>As-As and Ge-Ge forbidden</th>
<th>As-As, Ge-Ge, Se-Se and Ge-As forbidden</th>
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<tr>
<td>(R_c)</td>
<td>1</td>
<td>1.005</td>
<td>1.057</td>
<td>1.292</td>
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</table>
Table 4. Comparison of the coordination numbers of Ge$_{22}$As$_{20}$Se$_{58}$ and Ge$_2$Sb$_2$Te$_5$ [36] with those of the respective IV-VI random covalent networks (in parentheses)

<table>
<thead>
<tr>
<th></th>
<th>Ge-Ge</th>
<th>Ge-As/Ge-Sb</th>
<th>Ge-Se/Ge-Te</th>
<th>As-As/Sb-Se</th>
<th>As-Se/Sb-Te</th>
<th>Se-Se/Te-Te</th>
</tr>
</thead>
<tbody>
<tr>
<td>Ge$<em>{22}$As$</em>{20}$Se$_{58}$</td>
<td>1.46 (1.33)</td>
<td>0.88 (0.89)</td>
<td>1.69 (1.78)</td>
<td>0.66 (0.68)</td>
<td>1.41 (1.32)</td>
<td>0.93 (0.88)</td>
</tr>
<tr>
<td>Ge$_2$Sb$_2$Te$_5$</td>
<td>0.79 (1.33)</td>
<td>0.60 (1.0)</td>
<td>2.45 (1.67)</td>
<td>0 (0.75)</td>
<td>2.53 (1.25)</td>
<td>0 (0.83)</td>
</tr>
</tbody>
</table>
Figure Captions

Figure 1. X-ray diffraction structure factors of Ge\textsubscript{10}As\textsubscript{10}Se\textsubscript{80}, Ge\textsubscript{22.5}As\textsubscript{10}Se\textsubscript{67.5} and Ge\textsubscript{33}As\textsubscript{20}Se\textsubscript{47}

Figure 2. Ge, As and Se K-edge $k^2$X curves of Ge\textsubscript{10}As\textsubscript{10}Se\textsubscript{80}, Ge\textsubscript{22.5}As\textsubscript{10}Se\textsubscript{67.5} and Ge\textsubscript{33}As\textsubscript{20}Se\textsubscript{47}

Figure 3. X-ray diffraction fit of Ge\textsubscript{27.5}As\textsubscript{10}Se\textsubscript{62.5}

Figure 4. Ge, As and Se K-edge EXAFS fits of Ge\textsubscript{27.5}As\textsubscript{10}Se\textsubscript{62.5}

Figure 5. Partial pair distribution functions of Ge\textsubscript{27.5}As\textsubscript{10}Se\textsubscript{62.5}

Figure 6. Se K-edge EXAFS fits of Ge\textsubscript{33}As\textsubscript{20}Se\textsubscript{47} glass with and without Se-Se bonds

Figure 7. (a) Nonlinear refractive index $n_2$ of the Ge-As-Se glasses measured at 1500 nm [44]; (b) fraction of different bonds in the Ge\textsubscript{x}As\textsubscript{10}Se\textsubscript{90-x} glasses. To extend the mean coordination number region value of Ge\textsubscript{33}As\textsubscript{20}Se\textsubscript{47} are also shown (highest MCN); $\phi_{\text{SeSe}}$ – Se-Se bonds, $\phi_{\text{GeGe}}+\phi_{\text{GeAs}}$ – Ge-Ge and Ge-As bonds, $\phi_{\text{tot}}$ – total fraction of Ge-Ge, As-As, Se-Se and Ge-As bonds. The lines are guides for the eye.
Figure 1.
Figure 2.
Figure 3.
Figure 4.
Figure 5.
Figure 6.

Se K-edge with Se-Se bonds

$\kappa^2 (k)$

RMC
exp

Se K-edge without Se-Se bonds

$\kappa^2 (k)$
Figure 7.